

Medium power transistor (60V, 2A)

2SC5866

●**Features**

- 1) High speed switching. (Tf : Typ. : 35ns at Ic = 2A)
- 2) Low saturation voltage, typically
(Typ. : 200mV at Ic = 1.0A, IB = 0.1A)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2094

●**Applications**

Low frequency amplifier
High speed switching

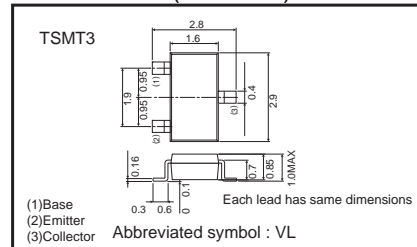
●**Structure**

NPN Silicon epitaxial planar transistor

●**Packaging specifications**

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
2SC5866		○

●**Dimensions (Unit : mm)**



●**Absolute maximum ratings (Ta=25°C)**

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CE0}	60	V
Emitter-base voltage	V _{EB0}	6	V
Collector current	I _c	2	A
	I _{cP}	4	A *1
Power dissipation	P _c	500	mW *2
Junction temperature	T _J	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

*1 Pw=10ms

*2 Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	60	-	-	V	$I_C=100\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	60	-	-	V	$I_C=1mA$
Emitter-base breakdown voltage	BV_{EBO}	6	-	-	V	$I_E=100\mu A$
Collector cut-off current	I_{CBO}	-	-	1.0	μA	$V_{CB}=40V$
Emitter cut-off current	I_{EBO}	-	-	1.0	μA	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	200	500	mV	$I_C=1A, I_B=0.1A$ *1
DC current gain	h_{FE}	120	-	390	-	$V_{CE}=2V, I_C=100mA$
Transition frequency	fT	-	200	-	MHz	$V_{CE}=10V, I_E=-100mA, f=10MHz$ *1
Collector output capacitance	C_{ob}	-	10	-	pF	$V_{CB}=10V, I_E=0mA, f=1MHz$
Turn-on time	T_{on}	-	50	-	ns	$I_C=2A,$ $I_{B1}=2000mA$
Storage time	T_{stg}	-	120	-	ns	$I_{B2}=-200mA$
Fall time	T_f	-	35	-	ns	$V_{CC}=25V$ *2

*1 Non repetitive pulse

*2 See switching characteristics measurement circuits

●hFE RANK

Q	R
120-270	180-390

●Electrical characteristic curves

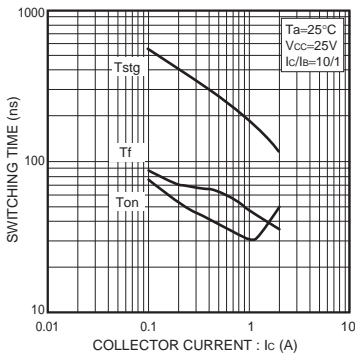


Fig.1 Switching Time

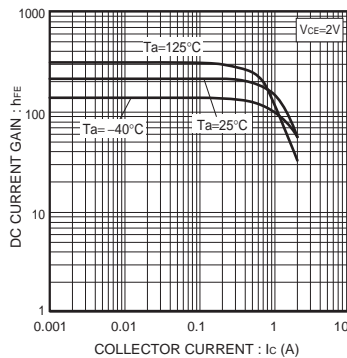


Fig.2 DC current gain vs. collector current

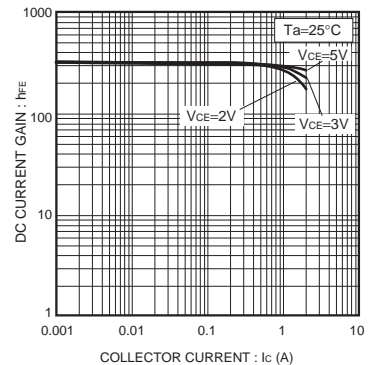


Fig.3 DC current gain vs. collector current

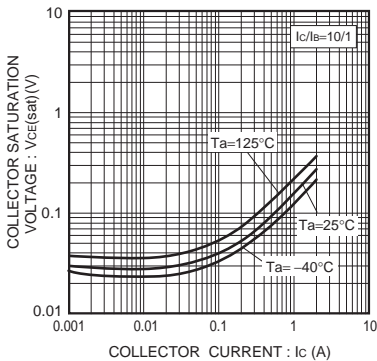


Fig.4 Collector-emitter saturation voltage vs. Collector Current

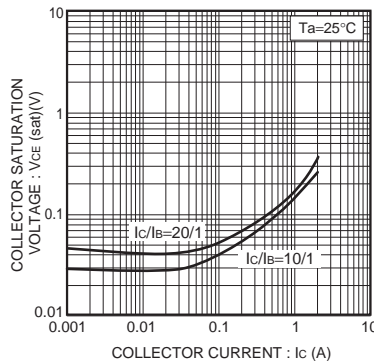


Fig.5 Collector-emitter saturation voltage vs. collector current

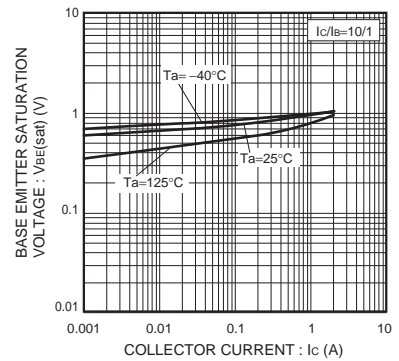


Fig.6 Base-emitter saturation voltage vs. collector current

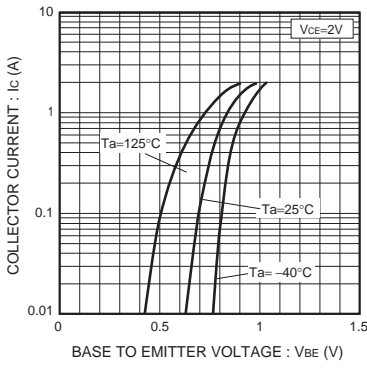


Fig.7 Ground emitter propagation characteristics

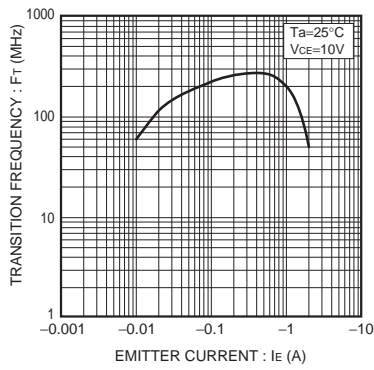


Fig.8 Transition frequency

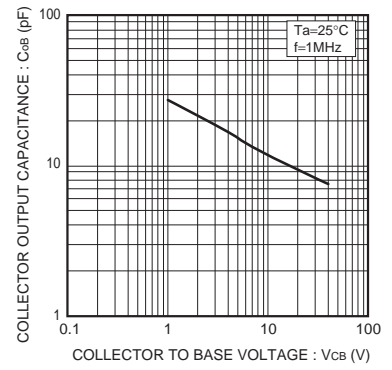
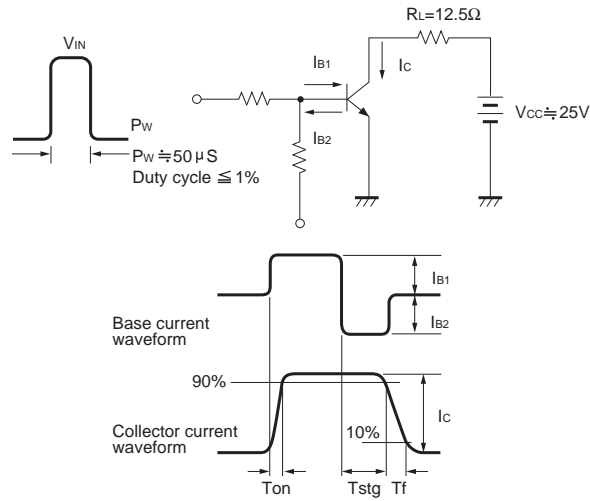


Fig.9 Collector output capacitance

●Switching characteristics measurement circuits



Notes

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